

Serial Nr.: 10/633,029  
Art Unit: 2818

03180-URS

REMARKS

In the Office Action, claim 1 is objected to because the limitation "a p-type quantum-dot epitaxial layer made of an InAlN compound" is not supported by the specification.

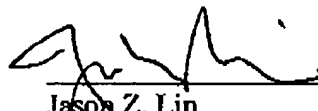
In response, paragraph [0013] is now amended to specifically describe that the p-type quantum-dot epitaxial layer is made of an InAlN compound as shown in the above amendment.

Claim 1 is also amended to correct an informality.

Claims 2-6 are cancelled as a result of the Election/Restriction requirement of office action on 3/8/2005.

The above amendment has been made without prejudice. Claim 1 is now in full condition for allowance. The specification has also been amended to correct a few editorial and grammatical errors. Applicant respectfully requests that a timely Notice of Allowance be issued for this application.

Respectfully submitted,

  
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